

NCE0203S

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE0203S uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

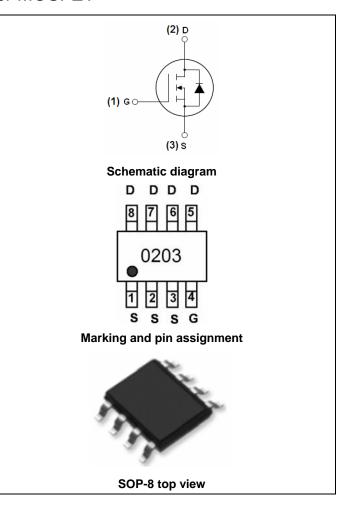
General Features

- V_{DS} =200V, I_{D} =3.9A $R_{DS(ON)} < 79m\Omega$ @ V_{GS} =10V (Typ: 56m Ω)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Low gate to drain charge to reduce switching losses

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% ΔVds TESTED!



Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|----------|----------------|-----------|------------|------------|
| 0203 | NCE0203S | SOP-8 | Ø330mm | 12mm | 2500 units |

Absolute Maximum Ratings (T_A=25 ℃unless otherwise noted)

| Parameter | Symbol | Limit | Unit | |
|--|----------------------------------|------------|------|--|
| Drain-Source Voltage | V _{DS} | 200 | V | |
| Gate-Source Voltage | V _{GS} | ±20 | V | |
| Drain Current-Continuous | I _D | 3.9 | А | |
| Drain Current-Continuous(T _C =100 °C) | I _D (100℃) | 3 | Α | |
| Pulsed Drain Current | I _{DM} | 30 | А | |
| Maximum Power Dissipation | P _D | 3 | W | |
| Operating Junction and Storage Temperature Range | T _J ,T _{STG} | -55 To 150 | °C | |

Thermal Characteristic

| Thermal Resistance, Junction-to-Case (Note 2) | $R_{	heta JC}$ | 41.7 | °C/W |
|---|----------------|------|------|



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Electrical Characteristics (T_A=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|---------------------|---|-----|------|------|------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250μA | 200 | 215 | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =200V,V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V _{GS} =±20V,V _{DS} =0V | - | - | ±100 | nA |
| On Characteristics (Note 3) | · | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=250\mu A$ | 2 | 3 | 4 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =10V, I _D =3.7A | - | 56 | 79 | mΩ |
| Forward Transconductance | g FS | V _{DS} =50V,I _D =3.9A | 7 | - | - | S |
| Dynamic Characteristics (Note4) | | | • | | 1 | |
| Input Capacitance | C _{lss} | \/ O5\/\/ O\/ | | 4200 | | PF |
| Output Capacitance | Coss | V_{DS} =25V, V_{GS} =0V, F=1.0MHz | | 163 | | PF |
| Reverse Transfer Capacitance | C _{rss} | F=1.UIVIFIZ | | 75 | | PF |
| Switching Characteristics (Note 4) | | | | | | |
| Turn-on Delay Time | t _{d(on)} | | - | 15 | - | nS |
| Turn-on Rise Time | t _r | V_{DD} =100 V , I_{D} =2.2 A | - | 13 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | V_{GS} =10V, R_{GEN} =6.5 Ω | - | 26 | - | nS |
| Turn-Off Fall Time | t _f | | - | 14 | - | nS |
| Total Gate Charge | Qg | \/ -100\/ -2.24 | - | 38 | - | nC |
| Gate-Source Charge | Q _{gs} | V_{DS} =100V, I_{D} =2.2A, V_{GS} =10V | - | 9 | - | nC |
| Gate-Drain Charge | Q _{gd} | VGS-IUV | - | 15 | - | nC |
| Drain-Source Diode Characteristics | | | | | | |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =3.7A | - | - | 1.2 | V |
| Diode Forward Current (Note 2) | Is | | - | - | 4 | Α |

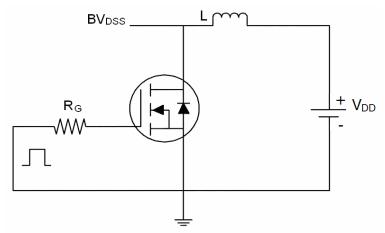
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤ 300μ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production

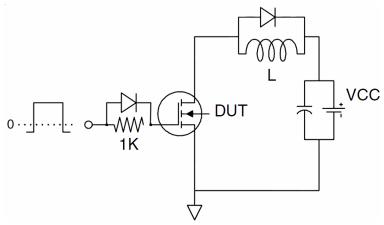
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Test Circuit

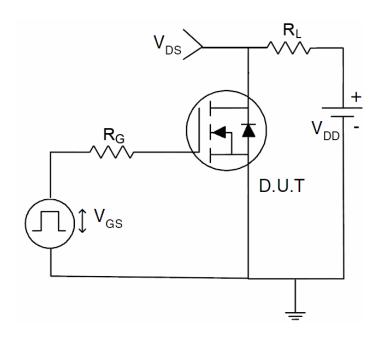
1) E_{AS} test Circuit



2) Gate charge test Circuit

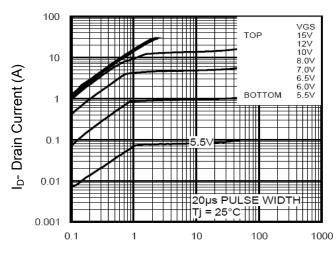


3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)



Vds Drain-Source Voltage (V)

Figure 1 Output Characteristics

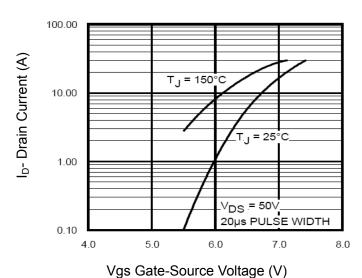


Figure 2 Transfer Characteristics

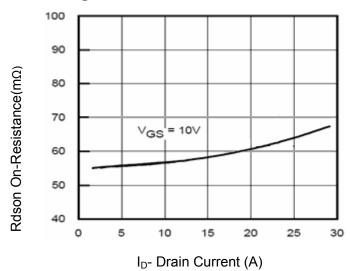


Figure 3 Rdson- Drain Current

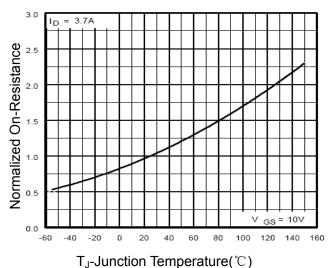


Figure 4 Rdson-JunctionTemperature

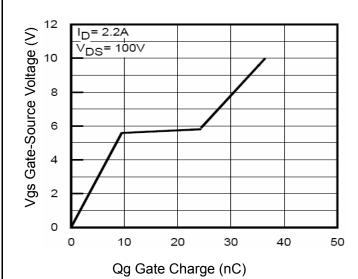


Figure 5 Gate Charge

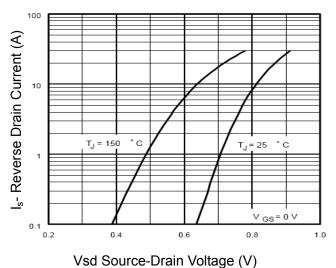


Figure 6 Source- Drain Diode Forward



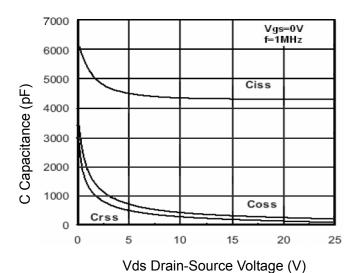
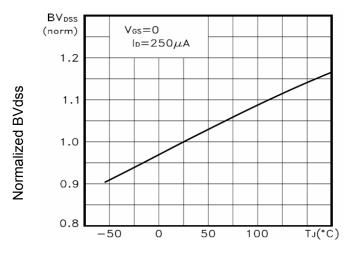


Figure 7 Capacitance vs Vds



 T_J -Junction Temperature (°C) Figure 9 BV_{DSS} vs Junction Temperature

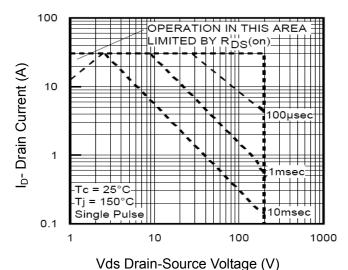
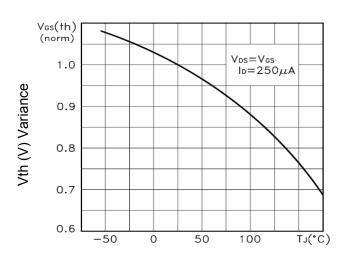


Figure 8 Safe Operation Area



T_J-Junction Temperature(°C)

Figure 10 V_{GS(th)} vs Junction Temperature

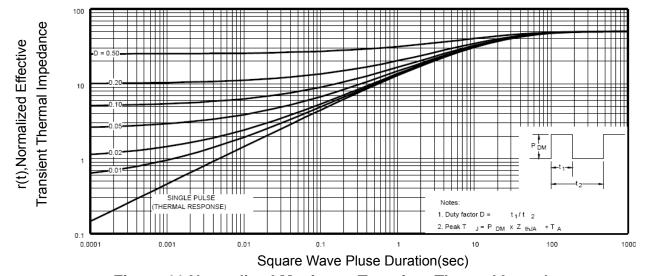
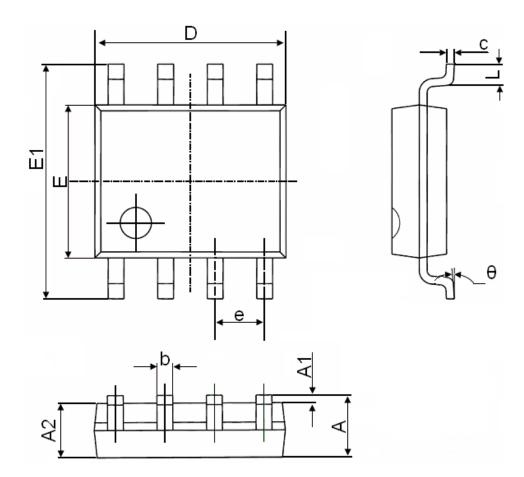


Figure 11 Normalized Maximum Transient Thermal Impedance

Pb Free Product

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SOP-8 Package Information



| Symbol | Dimensions | In Millimeters | Dimensions In Inches | | |
|--------|------------|----------------|----------------------|-------|--|
| | Min. | Max. | Min. | Max. | |
| A | 1.350 | 1.750 | 0.053 | 0.069 | |
| A1 | 0.100 | 0.250 | 0.004 | 0.010 | |
| A2 | 1.350 | 1.550 | 0.053 | 0.061 | |
| b | 0.330 | 0.510 | 0.013 | 0.020 | |
| С | 0.170 | 0.250 | 0.006 | 0.010 | |
| D | 4.700 | 5.100 | 0.185 | 0.200 | |
| Е | 3.800 | 4.000 | 0.150 | 0.157 | |
| E1 | 5.800 | 6.200 | 0.228 | 0.244 | |
| е | 1.270 | (BSC) | 0.050(BSC) | | |
| L | 0.400 | 1.270 | 0.016 | 0.050 | |
| θ | 0° | 8° | 0° | 8° | |



http://www.ncepower.com

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